

HER501 THRU HER508



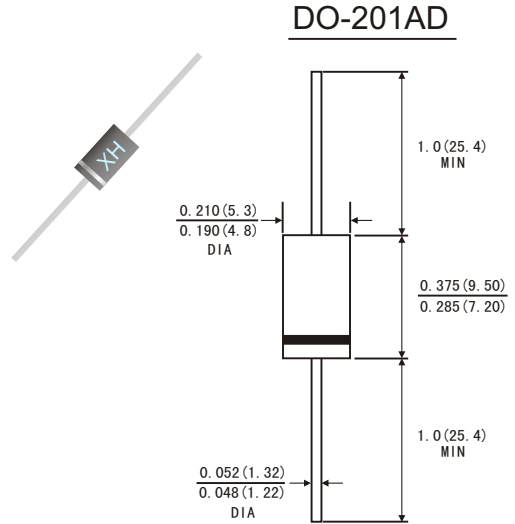
HIGH EFFICIENCY RECTIFIER
Reverse Voltage: 50 to 1000 Volts
Forward Current: 5.0 Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Low forward voltage drop
- High current capability, High reliability
- Low power loss, high efficiency
- High surge current capability
- High speed switching, Low leakage
- High temperature soldering guaranteed: 260 °C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

MECHANICAL DATA

- Case: JEDEC DO-201AD molded plastic body
- Epoxy: UL94V-0 rate flame retardant
- Lead: Plated axial leads, solderable per MIL-STD-750, method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.042ounce, 1.19 grams



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.)

	Symbols	HER 501	HER 502	HER 503	HER 504	HER 505	HER 506	HER 507	HER 508	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	300	400	600	800	1000	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	210	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	300	400	600	800	1000	Volts
Maximum Average Forward Rectified Current 0.375"(9.5mm)lead length at T _A =55°C	I _(AV)	5.0								Amps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	200.0								Amps
Maximum Instantaneous Forward Voltage at 5.0 A	V _F	1.0		1.3		1.85			Volts	
Maximum DC Reverse Current at rated DC blocking voltage	T _A =25°C	10.0								µA
	T _A =100°C	200								
Maximum reverse recovery time(Note1)	T _{rr}	50					75			ns
Typical junction capacitance(Note2)	C _J	75								PF
Operating junction and storage temperature range	T _J T _{STG}	-65 to +150								°C

Note: 1. Test conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A.

2. Measured at 1MHz and applied reverse voltage of 4.0 Volts.

FIG.1-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

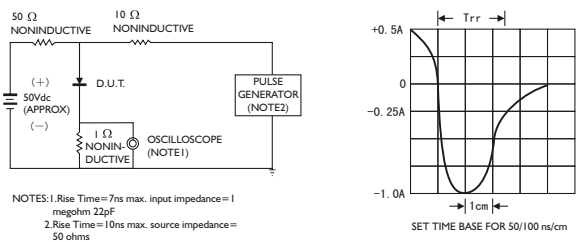


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

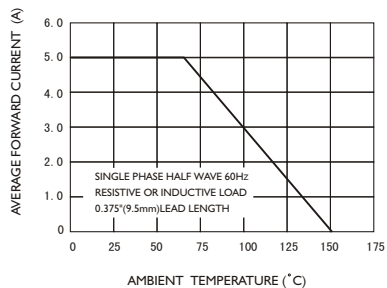


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

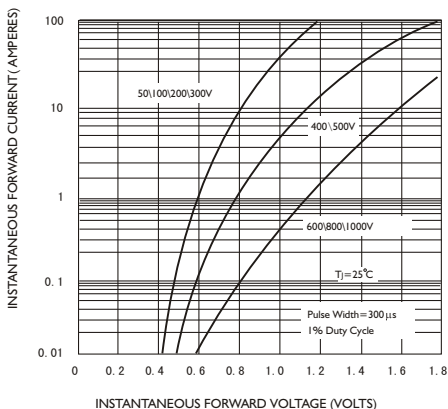


FIG.4-TYPICAL REVERSE CHARACTERISTICS

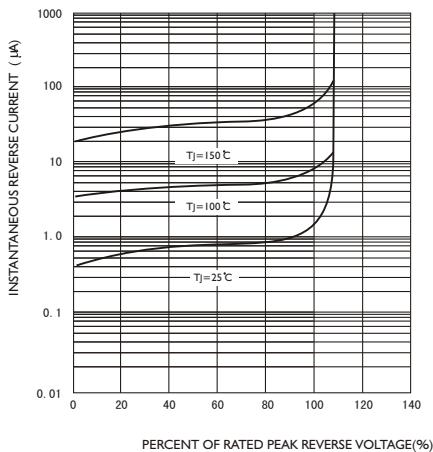


FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

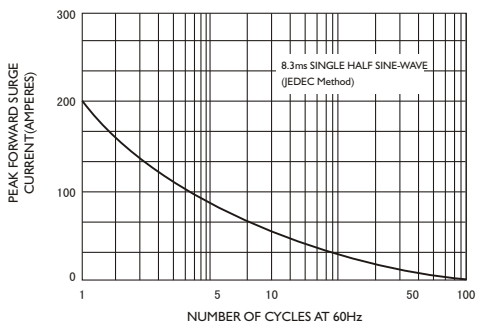


FIG.6-TYPICAL JUNCTION CAPACITANCE

